





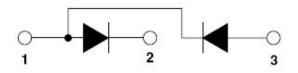
SM400T200D1 SCHOTTKY RECTIFIER



Features

- 175°C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- UL approved file E517293
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- · High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings@T_J=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V	
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _C =101°C, rectangular wave form	200(Per Leg)	Α	
			400(Per Device)	A	
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half Sine pulse	2840	Α	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.8 A, L = 10 mH	15	mJ	
Repetitive avalanche current	lar	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x VR typical	1	А	

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







Electrical Characteristics@T_=25°C unless otherwise specified

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 200A, Pulse, T _J = 25 °C @ 400A, Pulse, T _J = 25 °C	0.90 1.02	0.99 1.15	V
	V _{F2}	@ 200A, Pulse, T _J = 125 °C @ 400A, Pulse, T _J = 125 °C	0.78 0.93	0.82 0.97	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = \text{rated } V_{R_i} T_J = 25 ^{\circ}\text{C}$	0.02	6	mA
	I _{R2}	$@V_R = \text{rated } V_{R_i} T_J = 125 ^{\circ}\text{C}$	6	85	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	2870	5200	pF
Insulation Voltage	Visol	Ac. 50HZ; R.M.S; 1min	-	3000	V
		Ac. 50HZ; R.M.S; 1sec	-	3500	l v
Maximum voltage rate of change	dV/dt	Rated V _R	-	10000	V/µs

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications@T_J=25°C unless otherwise specified

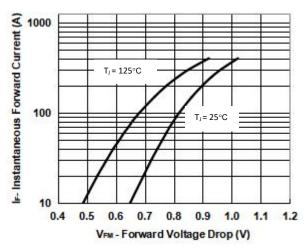
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Maximum internal thermal resistance, junction to case per leg	R _{th(J-C)}	DC operation	0.32	°C/W
Typical thermal resistance, case to heatsink per module	R _{th(C-S)}	-	0.1	°C/W
Mounting Torque ±15%	T _M	-	Mounting 5 Torque(M6)	Nm
			Terminal 4 Torque(M5)	
Module(Approximately)	Weight	-	100	g







Ratings and Characteristics Curves



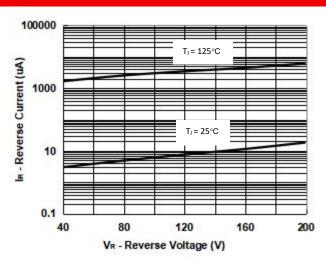


Fig. 1 - Typical Forward Characteristics

Fig. 2 - Typical Reverse Characteristics

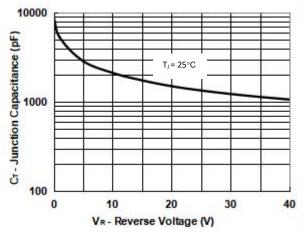


Fig. 3 - Typical Junction Capacitance

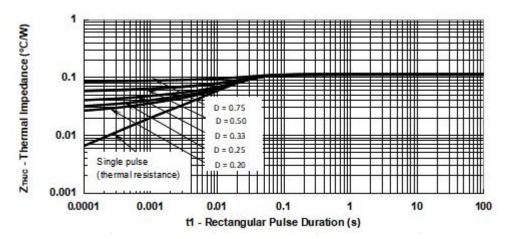


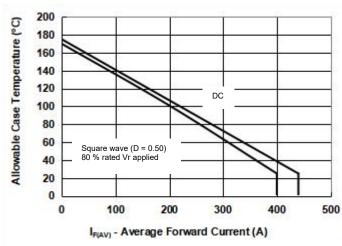
Fig. 4 Typical Thermal Impedance Z_{thJC} Characteristics (Per Leg)

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •









300 250 D = 0.20Average Power Loss (W) D = 0.25200 D = 0.33D = 0.75 150 D = 0.50100 50 0 100 150 200 250 300 50 0 I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current (Per Leg)

Fig.6 - Forward Power Loss Characteristics (Per Leg)

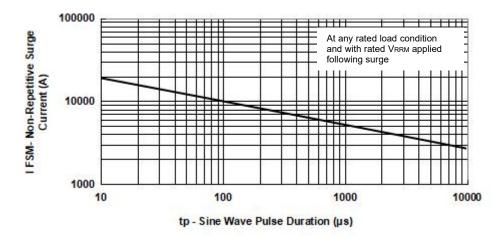


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

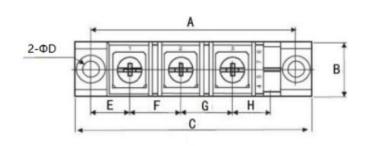
(1) Formula used: $T_C = T_J - (P_d + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6)$; $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \% rated V_R$

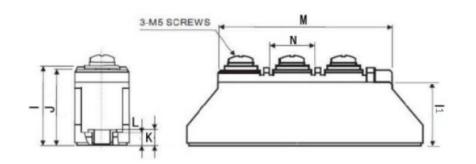






Mechanical Dimensions T1 (Millimeters)



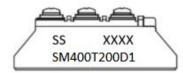


OVMDOL	Millimeters		
SYMBOL	Min.	Max.	
Α	79.5	80.5	
В	20.8	21.2	
С	91.35	92.75	
ΦD	6.1	6.5	
E	14.5	15.5	
F	19.5	20.5	
G	19.5	20.5	
Н	14.5	15.5	
I	30.5	31.5	
I1	24	25	
J	29	30	
K	5.7	6.3	
L	4.7	5.3	
М	67.5	68.5	
N	17.5	18.5	

Ordering Information

Device	Package	Shipping
SM400T200D1	T1	14pcs/ box

Marking Diagram



Where XXXX is YYWW

 SM400T200D1
 = Part name

 SS
 = SS

 YY
 = Year

 WW
 = Week

Cautions: Molding resin Epoxy resin UL:94V-0









DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..